Sidac High Voltage

Bidirectional Triggers

Bidirectional devices designed for direct interface with the ac power line. Upon reaching the breakover voltage in each direction, the device switches from a blocking state to a low voltage on-state. Conduction will continue like a Triac until the main terminal current drops below the holding current. The plastic axial lead package provides high pulse current capability at low cost. Glass passivation insures reliable operation.

Features

- High Pressure Sodium Vapor Lighting
- Strobes and Flashers
- Ignitors
- High Voltage Regulators
- Pulse Generators
- Used to Trigger Gates of SCR's and Triacs
- **%** Indicates UL Registered File #E210057
- These are Pb-Free Devices*

MAXIMUM RATINGS (T_J = $25^{\circ}C$ unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Off–State Voltage (Sine Wave, 50 to 60 Hz, T_J = – 40 to 125°C) MKP1V120, MKP1V130, MKP1V160 MKP1V240		±90 ±180	V
On-State Current RMS (T _L = 80°C, Lead Length = 3/8", All Conduction Angles)	I _{T(RMS)}	±0.9	A
Peak Non-repetitive Surge Current (60 Hz One Cycle Sine Wave, T _J = 125°C)	I _{TSM}	±4.0	A
Operating Junction Temperature Range	TJ	-40 to +125	°C
Storage Temperature Range	T _{stg}	-40 to +150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Lead Lead Length = 3/8"	$R_{\theta JL}$	40	°C/W
Lead Solder Temperature (Lead Length \geq 1/16" from Case, 10 s Max)	ΤL	260	°C

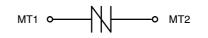
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



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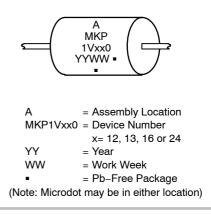
http://onsemi.com

SIDACS(9\) 0.9 AMPERES RMS 120 - 240 VOLTS





MARKING DIAGRAM



ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

Characteristic	Symbol	Min	Тур	Max	Unit
DFF CHARACTERISTICS		•	•		
Repetitive Peak Off–State Current $T_J = 25^{\circ}C$ (50 to 60 Hz Sine Wave) $V_{DRM} = 90 V$, MKP1V120, MKP1V130 and MKP1V160 $V_{DRM} = 180 V$, MKP1V240	I _{DRM}	-	_	5.0	μΑ
ON CHARACTERISTICS					
	V _{BO}	110 120 150 220		130 140 170 250	V
Peak On–State Voltage (I_{TM} = 1 A Peak, Pulse Width \leq 300 µs, Duty Cycle \leq 2%)	V _{TM}	-	1.3	1.5	V
Dynamic Holding Current (Sine Wave, 50 to 60 Hz, R _L = 100 Ohm)	I _H	-	_	100	mA
Switching Resistance (Sine Wave, 50 to 60 Hz)	R _S	0.1	-	_	kΩ
DYNAMIC CHARACTERISTICS					•
Critical Rate-of-Rise of On-State Current, Critical Damped Waveform Circuit (I _{PK} = 130 Amps, Pulse Width = 10 μsec)	di/dt	-	120	-	A/μs

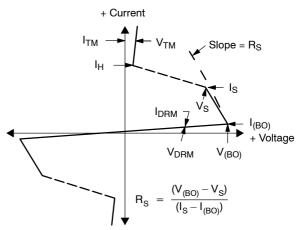
ORDERING INFORMATION

Device	Package*	Shipping [†]	
MKP1V120RLG	DO-41, Axial Lead	5000 / Tape & Reel	
MKP1V130RLG		5000 / Tape & Reel	
MKP1V160G		1000 Units / Bulk	
MKP1V160RLG		5000 / Tape & Reel	
MKP1V240G		1000 Units / Bulk	
MKP1V240RLG		5000 / Tape & Reel	

*This package is inherently Pb-Free. †For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Voltage Current Characteristic of SIDAC (Bidirectional Device)

Symbol	Parameter
I _{DRM}	Off State Leakage Current
V _{DRM}	Off State Repetitive Blocking Voltage
V _{BO}	Breakover Voltage
I _{BO}	Breakover Current
Ι _Η	Holding Current
V _{TM}	On State Voltage
I _{TM}	Peak on State Current



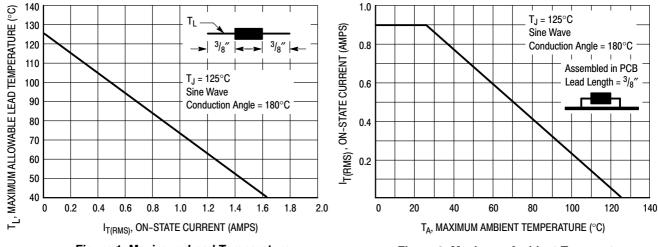
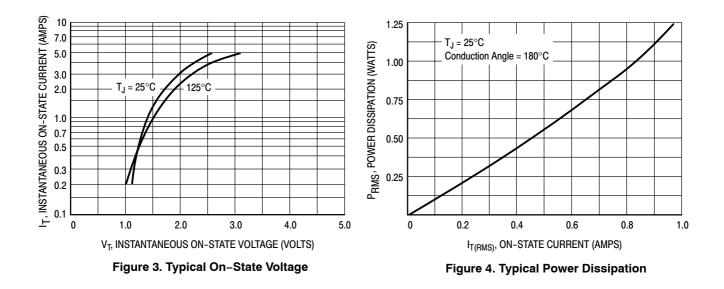


Figure 1. Maximum Lead Temperature





THERMAL CHARACTERISTICS

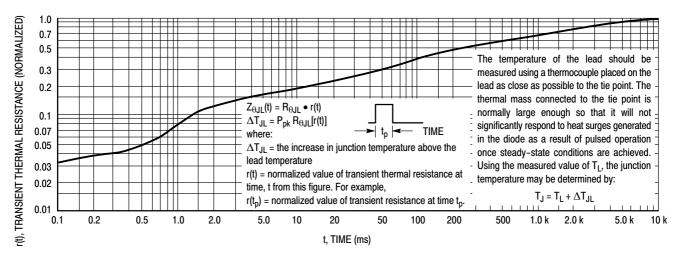
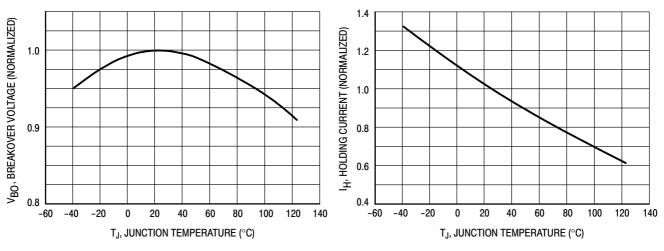


Figure 5. Thermal Response







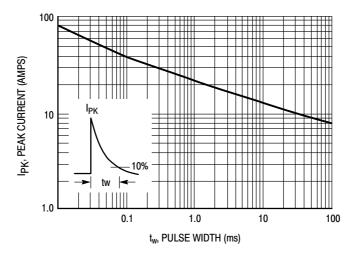
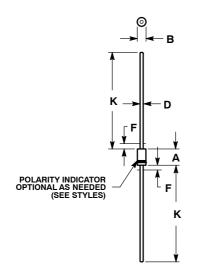


Figure 8. Pulse Rating Curve

PACKAGE DIMENSIONS

AXIAL LEAD CASE 59–10 ISSUE U



NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI

- Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.
- 3. ALL RULES AND NOTES ASSOCIATED WITH
- JEDEC DO-41 OUTLINE SHALL APPLY 4. POLARITY DENOTED BY CATHODE BAND.
- 5. LEAD DIAMETER NOT CONTROLLED WITHIN F DIMENSION.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.161	0.205	4.10	5.20
В	0.079	0.106	2.00	2.70
D	0.028	0.034	0.71	0.86
F		0.050		1.27
ĸ	1.000		25.40	

STYLE 2: NO POLARITY

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